SCAS272 - JANUARY 1993 - REVISED MARCH 1994

 Member of the Texas Instruments Widebus[™] Family 		DGG OR DL PACKAGE (TOP VIEW)	
 EPIC ™ (Enhanced-Performance Implanted CMOS) Submicron Process 		56 10E2	
 Designed to Facilitate Incident-Wave Switching for Line Impedances of 50 Ω or Greater 	1Y1 2 1Y2 3 GND 4	55 1A1 54 1A2 53 GND 52 1A3	
 Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C 	1Y3 5 1Y4 6 V _{CC} 7	52 0 1A3 51 0 A14 50 0 V _{CC}	
 Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at V_{CC} = 3.3 V, T_A = 25°C 	1Y5 8 1Y6 9	49 1A5 48 1A6	
 Bus-Hold On Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors 	1Y7 0 10 GND 0 11 1Y8 0 12	47 1A7 46 GND 45 1A8	
 Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages 	1Y9 [13 1Y10 [14 2Y1 [15	44] 1A9 43] 1A10 42] 2A1	
description	2Y2 16 2Y3 17	41 2A2 40 2A3	
This 20-bit noninverting buffer/driver is designed for 2.7-V to 3.6-V V_{CC} operation.	GND 18 2Y4 19 2Y5 20	39 GND 38 2A4 37 2A5	
The SN74ALVC16827 is composed of two 10-bit sections with separate output-enable signals. For	2Y6	36 2A6 35 V _{CC}	
either 10-bit buffer section, the two output-enable $(1\overline{OE1} \text{ and } 1\overline{OE2} \text{ or } 2\overline{OE1} \text{ and } 2\overline{OE2})$ inputs must both be low for the corresponding Y outputs to be	2Y7 23 2Y8 24 GND 25	34 2A7 33 2A8 32 GND	
active. If either output-enable input is high, the outputs of that 10-bit buffer section are in the high-impedance state.	2Y9 2 2Y10 27 2OE1 28	31 2A9 30 2A10 29 2OE2	

FUNCTION TABLE	
(each 10-bit section)	

	INPUTS		OUTPUT	
OE1	OE2	Α	Y	
L	L	L	L	
L	L	Н	н	
н	Х	Х	Z	
Х	Н	Х	Z	

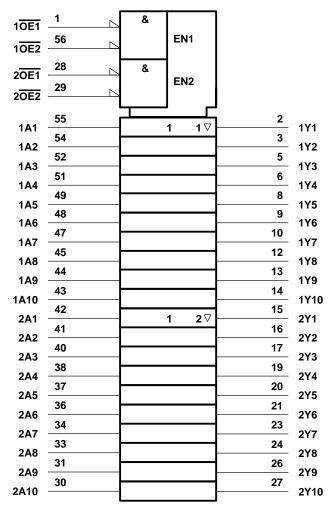
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The SN74ALVC16827 is available in TI's shrink small-outline (DL) and thin shrink small-outline (DGG) packages, which provide twice the I/O pin count and functionality of standard small-outline packages in the same printed-circuit-board area. The SN74ALVC16827 is characterized for

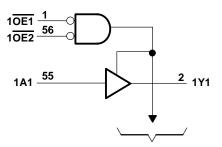
operation from -40°C to 85°C.

SCAS272 - JANUARY 1993 - REVISED MARCH 1994

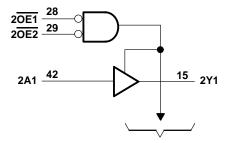
logic symbol[†]



logic diagram (positive logic)



To Nine Other Channels



To Nine Other Channels

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



SCAS272 - JANUARY 1993 - REVISED MARCH 1994

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	
Output voltage range, V _O (see Notes 1 and 2)	-0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 3)	: DGG package 1 W
	DL package 1.4 W
Storage temperature range	−65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 4.6 V maximum.

3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the *Package Thermal Considerations* application note.

recommended operating conditions

			MIN	MAX	UNIT
V _{CC}	Supply voltage	ply voltage		3.6	V
VIH	High-level input voltage	V_{CC} = 2.7 V to 3.6 V	2		V
VIL	Low-level input voltage	V_{CC} = 2.7 V to 3.6 V		0.8	V
VI	Input voltage		0	VCC	V
VO	Output voltage		0	VCC	V
ЮН	High-level output current	$V_{CC} = 2.7 V$		-12	mA
		V _{CC} = 3 V		-24	
	Low-level output current	V _{CC} = 2.7 V		12	- mA
IOL		V _{CC} = 3 V		24	
$\Delta t/\Delta v$	Input transition rise or fall rate		0	10	ns/V
TA	Operating free-air temperature		-40	85	°C



SCAS272 - JANUARY 1993 - REVISED MARCH 1994

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc†	MIN MAX	UNIT
Vон	I _{OH} = -100 μA	MIN to MAX	V _{CC} -0.2	
	10 m A	2.7 V	2.2	V
	$I_{OH} = -12 \text{ mA}$	3 V	2.4	
	$I_{OH} = -24 \text{ mA}$	3 V	2	
	I _{OL} = 100 μA	MIN to MAX	0.2	V
VOL	I _{OL} = 12 mA	2.7 V	0.4	
	I _{OL} = 24 mA	3 V	0.55	
lj	$V_{I} = V_{CC}$ or GND	3.6 V	±5	μA
ha in	V _I = 0.8 V	3 V	75	μA
l(hold)	$V_{I} = 2 V$	3 V	-75	
I _{OZ}	$V_{O} = V_{CC}$ or GND	3.6 V	±10	μA
ICC	$V_{I} = V_{CC} \text{ or } GND,$ $I_{O} = 0$	3.6 V	40	μA
∆ICC	$V_{CC} = 3 V \text{ to } 3.6 V$, One input at $V_{CC} - 0.6 V$, Other inputs at V_{CC} or GND		750	μA
Ci	$V_{I} = V_{CC}$ or GND	3.3 V		pF
Co	$V_{O} = V_{CC}$ or GND	3.3 V		pF

[†] For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.



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